REV. Status A. Electrical specification (@ 25°C) 1. Power rating; REVISION 06/15/92 YS 500 mW 2. Dielectric strength; REVISION A 500 VDC 1 minute FLIPPED RADII 3. Insulation resistance; & CLARIFIED **MARKING** 10,000 MΩ MIN @ 500 VDC 06/24/05 YS 4. Turns ratio; $(1-2):(3-4):(5-6)=2:1:1\pm5\%$ REVISION B 5. Primary open circuit inductance; RoHS COMPLIANT 11/03/05 MP 400 μ H MIN @ 1 KHz, 40 mV (1-2) 6. Primary ET-constant REVISION C $8.5V-\mu s$ MIN NOTE 5: 400μH WAS 500μH 7. Rise time; 05/16/07 MP 5.6 ns MAX 8. Interwinding capacitance between primary and secondary; 11.0 PF MAX @ 100 KHz Date code 9. Primary leakage inductance with shorted secondary; 1.1 μ H MAX @ 100 KHz 10. DC Resistance; $(1-2) 1.3 \Omega$ Primary MAX Secondary (3-4) 0.7 Ω MAX Tertiary $(5-6) \ 0.7 \ \Omega \ MAX$ G507 TAM B. Marking; G507, TAM, date code and country of origin C. Schematic diagram PIN 1 Designation <u>PRI</u> 10 "TAM" and country of origin (molded) <u>SEC</u> 04 **TERT** ⊙6 D. Mechanical Specification G507 TAM 6.35(0.25) MAX ø 0.5 (0.02)-(Solderable 24 AWG) $9.5 \pm 2.5(0.374 \pm 0.100)$ Country of Origin $2.54 \pm 0.25(0.10 \pm 0.01)$ 8.9(0.35) MAX MAT $2.54 \pm 0.25(0.10 \pm 0.01)$ $10.2 \pm 0.5(0.40 \pm 0.02)$

PREPARED BY:

K. BRENNAN

SAFETY ENGINEER

B. OCONNELL

| IV. BIVEIVIO | | |
|--------------|---------------------|-----|
| ENGINEER: | DRAWING CONTROL NO. | REV |
| M. PITCHAI | P-A1-10633 | C |

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MODEL DESCRIPTION **PULSE TRANSFORMER**

TAMURA CORPORATION OF AMERICA 1040 SOUTH ANDREASEN DRIVE, #100 ESCONDIDO, CA. 92029 (951) 699-1270 FAX 7607400536

- 12.7(0.50) MAX

MODEL SPECIFICATION G507

DIM: mm[In] SCL: 2/1 SH: 1 OF

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